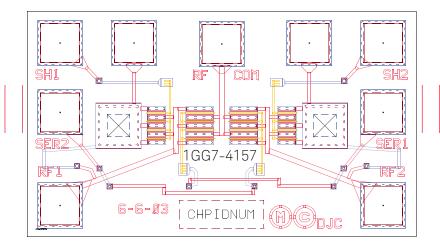
Keysight 1GG7-4157 DC - 20 GHz SPDT GaAs MMIC Switch



Data Sheet

Features

- Frequency range:
 DC-20 GHz, usable to
 26.5 GHz
- Insertion loss:1.4 dB typ @ 20 GHz
- Isolation:70 dB @ 45 MHz20 dB @ 20 GHz
- Return loss:15 dB typ
- Switching speed:< 1 ns (10%-90% RF)
- P_{_1dB}:
 25 dBm @ 10 MHz
 26 dBm @ 2 GHz
- Harmonics (DC coupled):
 SHI > 75 dBm typ
 THI > 50 dBm typ



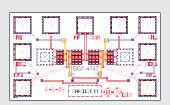
Description

The 1GG7-4157 is a GaAs monolithic microwave integrated circuit (MMIC) designed for low insertion loss and high isolation from DC to 20 GHz. It is intended for use as a general-purpose, single-pole, double-throw (SPDT), non-terminated switch. One series and one shunt MESFET per throw provide 2 dB maximum insertion loss and 20 dB typical isolation at 20 GHz. 1GG7-4157 chips use through-substrate vias to provide ground connections to the chip backside and minimize the number of wire bonds required.

Absolute maximum ratings¹

Symbol	Parameters/conditions	Min	Max	Units
V _{ser}	Series select voltages 1 & 2	-10.5	+10.5	volts
V _{sh}	Shunt select voltages 1 & 2	-10.5	+10.5	volts
P _{in}	RF input power		27	dBm
V _{in}	RF input DC voltage	-2.5	+2.5	volts
source	Current sourcing (sinking not allowed) at RF1 or RF2		60	mA
ESD	ESD level at any pad		300	volts
T _{op}	Operating temperature	-55	+125	°C
T _{st}	Storage temperature	-65	+165	°C
T _{max}	Maximum assembly temperature		+200	°C

^{1.} Operation in excess of any one of these may result in permanent damage to this device. T_A = 25 °C except for T_{op} , T_{st} , and T_{max} .



- Chip size: $690 \times 400 \mu m$ (27.2 × 15.7 mils)
- Chip size tolerance: ±10 μm (±0.4 mils)
- Chip thickness: 127 ±15 μ m (5.0 ±0.6 mils)
- Pad dimensions: $80 \times 80 \mu m$ (3.2 × 3.2 mils), or larger

DC specifications/physical properties

Symbol	Parameters/conditions	Min	Тур	Max	Units
R1/20N	Series FET "ON" resistance RFCOM to RF1/2	9	11.5	14	ohms
R1/20N	Shunt FET "ON" resistance at RF1/2	14	17.5	20.5	ohms
R1/20FF	Resistance at RF1/2 with all FETs "OFF"	9	11.9	15	Kohms
Isel1/2	Current with SER1/2 connected to SH2/1 at -10V		-16.6		μΑ
IG1/2	Current with SER1/2 connected to SH2/1 at +10V			21	μΑ
V_p	Pinchoff voltage ($V_{SEL2} = V_p, V_{RFout2} = +2 V$, $I_{RFout2} = 2 \text{ mA}, V_{SEI1} = -10 V, V_{RFout1} = \text{ open circuit}, V_{RFin} = \text{GND}$)	-7	-5	-3	volts

RF specifications

 $(T_A = 25 \text{ °C}, Z0 = 50 \Omega, V_{SEL-H} = +10 \text{ V}, V_{SEL-L} = -10 \text{ V})$

Symbol	Parameters/conditions	Min	Тур	Max	Units
BW	Guaranteed operating bandwidth	DC		20	GHz
IL	Insertion loss, RF _{COM} to selected RF _{out} (ON throw), 20 GHz		1.4	2.0	dB
ISO	Isolation, $\operatorname{RF}_{\operatorname{COM}}$ to unselected $\operatorname{RF}_{\operatorname{out}}$ (OFF throw), 20 GHz		20		dB
RL _{in}	Input return loss		15		dB
RL _{out-ON}	Output return loss, ON throw		15		dB
P _{-1dB}	Input power where IL Increases by 1 dB, $f_{in} = 2 \text{ GHz}$		25		dBm
t _s	Switching speed, 10%–90% RF envelope, $f_{in} = 2 \text{ GHz}$		10		ns
IL _t	Insertion loss temperature coefficient		-2.9		mdB/C

Applications

The 1GG7-4157 can be used in instrumentation, communications, radar, ECM, EW, and many other systems requiring SPDT switching. It can be used for pulse modulation, port isolation, transfer switching, high-speed switching, replacement of mechanical switches, and so on.

Assembly Techniques

GaAs MMICs are ESD sensitive. ESD preventive measures must be employed in all aspects of storage, handling, and assembly.

MMIC ESD precautions, handling considerations, die attach and bonding methods are critical factors in successful GaAs MMIC performance and reliability.

Keysight Technologies GaAs MMIC ESD, Die Attach and Bonding Guidelines - Application Note, literature number 5991-3484EN provides basic information on these subjects.

Additional References

Keysight Technologies FET Switch Speed and Settling Time - Application Note, literature number 5991–3516EN

S-Parameters¹

 $(T_A = 25 \text{ °C}, Z_0 = 50 \Omega, V_{\text{ser}} \text{ high} = 0 \text{ V}, V_{\text{ser}} \text{ low} = -10 \text{ V})$

Гиол		S11		(1.	S21 sertion		S31 (Isolation)		S22 ON thr			S33 OFF thr	a)
Freq GHz	dB	Mag	Ang	dB	isertion Mag		(Isolation)	dB	Mag		dB	(OFF thr Mag	ow) Ang
0.5	-18.85	0.11	8.14	-0.94	0.90	-2.46	-60.65	-18.87	0.11	4.91	-6.16	0.49	174.50
1.0	-19.39	0.11	12.17	-0.95	0.90	-4.59	-56.50	-18.87	0.11	5.40	-6.15	0.49	169.89
2.0	-20.46	0.09	17.08	-1.01	0.89	-8.85	-51.08	-19.50	0.11	9.93	-6.20	0.49	161.99
3.0	-19.15	0.11	22.32	-1.06	0.89	-12.73	-43.19	-18.74	0.12	20.94	-6.19	0.49	156.11
4.0	-16.68	0.15	21.56	-1.10	0.88	-16.68	-38.51	-17.52	0.13	25.80	-6.11	0.49	150.15
5.0	-15.29	0.17	24.96	-1.09	0.88	-20.58	-35.53	-15.88	0.16	25.28	-5.89	0.51	141.36
6.0	-15.72	0.16	32.66	-1.08	0.88	-24.46	-32.30	-15.20	0.17	19.63	-5.61	0.52	133.42
7.0	-17.98	0.13	24.18	-1.06	0.88	-28.73	-30.08	-16.92	0.14	11.64	-5.51	0.53	128.59
8.0	-16.64	0.15	10.40	-1.17	0.87	-33.37	-28.25	-16.67	0.15	11.70	-5.70	0.52	122.02
9.0	-13.33	0.22	16.88	-1.26	0.87	-37.24	-26.85	-13.94	0.20	19.60	-5.46	0.53	114.21
10.0	-13.24	0.22	18.95	-1.22	0.87	-40.59	-25.55	-13.56	0.21	22.10	-4.90	0.57	111.42
11.0	-15.07	0.18	10.39	-1.17	0.87	-44.37	-24.05	-15.41	0.17	14.89	-4.74	0.58	109.12
12.0	-16.63	0.15	9.21	-1.14	0.88	-48.83	-22.42	-16.80	0.14	5.89	-4.70	0.58	104.37
13.0	-18.84	0.11	-1.76	-1.18	0.87	-53.17	-21.31	-18.88	0.11	-3.66	-4.68	0.58	99.38
14.0	-17.93	0.13	-22.18	-1.27	0.86	-57.92	-21.08	-20.77	0.09	-4.83	-4.69	0.58	93.69
15.0	-15.44	0.17	-12.10	-1.47	0.84	-62.34	-20.55	-17.34	0.14	-0.66	-4.62	0.59	86.40
16.0	-16.48	0.15	-2.23	-1.31	0.86	-65.94	-19.96	-16.88	0.14	-9.92	-4.27	0.61	83.02
17.0	-24.58	0.06	-33.01	-1.21	0.87	-69.91	-19.50	-23.41	0.07	-6.10	-3.85	0.64	84.80
18.0	-21.77	0.08	-142.50	-1.19	0.87	-74.09	-19.11	-29.39	0.03	-170.97	-3.61	0.66	87.39
19.0	-17.73	0.13	-162.11	-1.25	0.87	-78.64	-18.69	-19.92	0.10	167.36	-3.65	0.66	80.53
20.0	-22.05	0.08	-138.47	-1.33	0.86	-85.95	-18.58	-29.75	0.03	86.53	-3.95	0.63	61.99
21.0	-28.92	0.04	-139.75	-1.55	0.84	-92.42	-18.36	-29.20	0.03	23.77	-3.75	0.65	55.73
22.0	-15.32	0.17	162.12	-1.79	0.81	-97.64	-18.85	-19.16	0.11	124.29	-3.37	0.68	64.63
23.0	-9.27	0.34	160.49	-2.23	0.77	-100.31	-18.89	-11.44	0.27	132.43	-3.00	0.71	75.57
24.0	-7.38	0.43	157.26	-2.59	0.74	-100.53	-19.47	-8.59	0.37	134.74	-3.04	0.70	80.66
25.0	-8.32	0.38	151.57	-2.18	0.78	-104.00	-19.24	-9.23	0.35	123.94	-3.71	0.65	64.91
26.0	-12.63	0.23	121.18	-1.90	0.80	-119.17	-19.20	-12.61	0.23	76.47	-3.56	0.66	31.36

Data from device mounted in modular breadboard. Bond wires on RF ports are approximately 15 mils long.
 Port 1 = RF Input, Port 2 = Selected RF Output (i.e., ON throw), and Port 3 = Unselected RF Output (i.e., OFF throw).

RoHS Compliance

This part is RoHS compliant, meeting the requirements of the EU *Restriction of Hazard-ous Substances* Directive 2011/65/EU, commonly known as *RoHS*. Six substances are regulated: lead, mercury, cadmium, chromium VI (hexavalent chromium), polybrominated biphenyls (PBB), and polybrominated biphenyl ethers (PBDE). RoHS compliance requires that any residual concentration of these substances is below the Directive's maximum concentration values (MCV): cadmium 100 ppm by weight and all others 1000 ppm by weight.

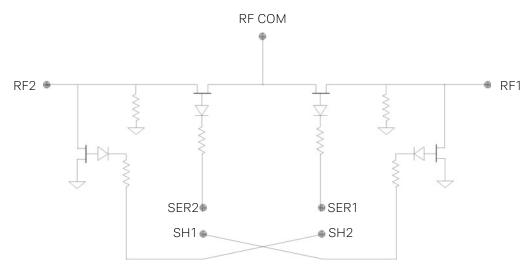


Figure 1. 1GG7-4157 Schematic

Recommended Operating Conditions

(Note: Isolating an RF port from DC ground with a blocking capacitor will result in non-zero DC potential at that port in its off-state, which can cause undesirable slow settling phenomenon in the reflection characteristic of that port in its off state. In this case, a DC path to ground should be provided on either the RFcom port and/or on both RF1/2 ports to accommodate leakage current from the FETs.)

	Se	elect line	RF path			
SER1	SH2	SER2	SH1	RF COM to RF1	RF COM to RF2	
-10 V	-10 V	+10 V	+10 V	Isolated	Low loss	
+10 V	+10 V	-10 V	-10 V	Low loss	Isolated	

Figure 2. 1GG7-4157 Switch Conditions ($T_A = 25 \, ^{\circ}\text{C}$)

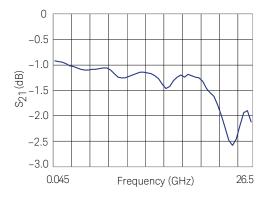


Figure 3. 1GG7-4157 insertion loss¹

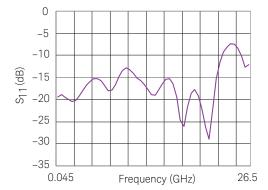


Figure 5. 1GG7-4157 input return loss¹

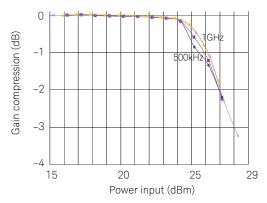


Figure 7. 1GG7-4157 gain compression²

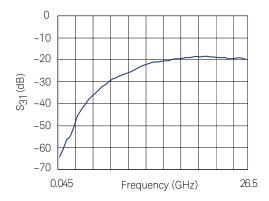


Figure 4. 1GG7-4157 input-to-output isolation¹

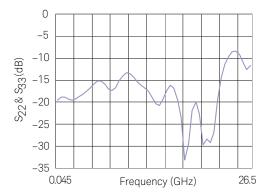


Figure 6. 1GG7-4157 output return loss¹

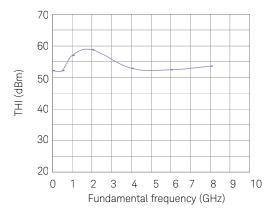


Figure 8. 1GG7-4157 harmonics^{2,3}

- 1. Data obtained from device in modular breadboard wire bonds are 15 mils on all RF ports.
- 2. All compression and harmonic data measured on individual device mounted in an Keysight 83040 Series Modular Microcircuit Package @ $T_{\rm case}$ = 25 °C.
- 3. Harmonic data points below -80 dBc are at or near the noise floor of the measurement system.

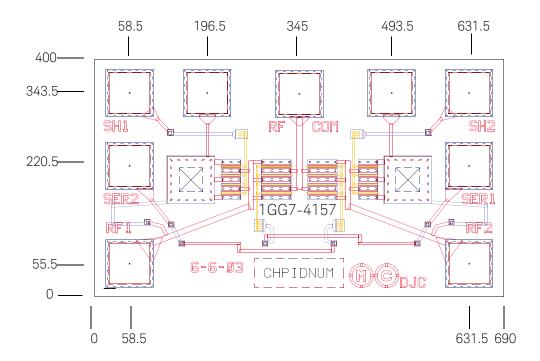


Figure 9. 1GG7-4157 bonding pad positions (shown in micrometers)

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The product described in this data sheet is RoHS Compliant. See RoHS Compliance section for more details.

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